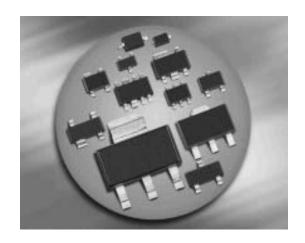


Silicon Tuning Diodes

- Extended frequency range up to 2.5 GHz;
 spezial design for use in TV-sat tuners
- High capacitance ratio
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101







BB833



Туре	Package	Configuration	L _S (nH)	Marking
BB833	SOD323	single	1.8	white X

Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Diode reverse voltage	V_{R}	30	V	
Peak reverse voltage-	V_{RM}	35		
$R \ge 5k\Omega$				
Forward current	/ _F	20	mA	
Operating temperature range	T_{op}	-55 150	°C	
Storage temperature	$T_{ m stg}$	-55 150		

¹Pb-containing package may be available upon special request



Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics		•	•		
Reverse current	I _R	-	-		nA
$V_{R} = 30 \text{ V}$		-	-	20	
$V_{R} = 30 \text{ V}, \ T_{A} = 85 \text{ °C}$				500	
AC Characteristics					
Diode capacitance	C_{T}				pF
$V_{R} = 1 \text{ V}, f = 1 \text{ MHz}$		8.5	9.3	10	
$V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$		0.6	0.75	0.9	
Capacitance ratio	C _{T1} /C _{T28}	11	12.4	-	
$V_{R} = 1 \text{ V}, V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$					
Capacitance matching ¹⁾	$\Delta C_{T}/C_{T}$	-	-	3	%
$V_{R} = 1 \text{ V}, V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$					
Series resistance	r _S	_	1.8	-	Ω
$V_{R} = 1 \text{ V}, f = 470 \text{ MHz}$					

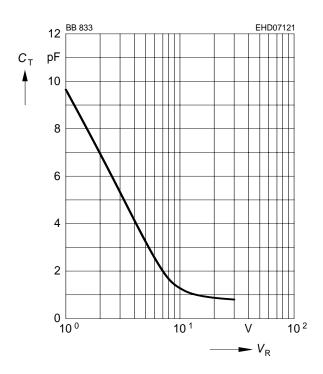
2

¹For details please refer to Application Note 047.

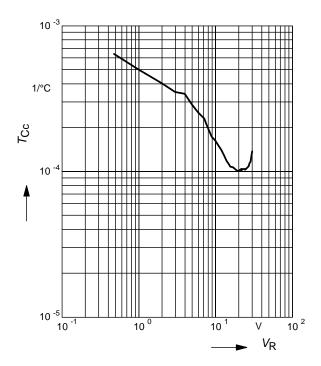


Diode capacitance $C_T = f(V_R)$

f = 1MHz



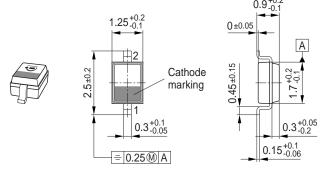
Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



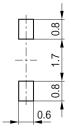
3 2007-04-20



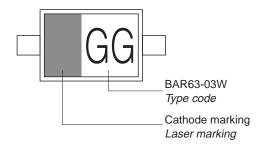
Package Outline



Foot Print

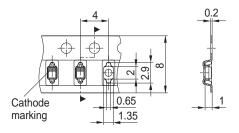


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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